

ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

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Title of Invention	METHOD TO PRODUCE TRANSISTOR HAVING REDUCED GATE HEIGHT
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Application Number :

Confirmation Number:

First Named Applicant: Heemyoung Park

Attorney Docket Number: FIS920030026US1

Art Unit:

Examiner:

Search string: (6429084 or 6198142 or 6303450 or 6248637 or 6432754 or 20020142551 or 20020164841 or 20020115240 or 20020072176).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	6429084	2002-08-06	Park, et al.			
	2	6198142	2001-03-06	Chau, et al.			
	3	6303450	2001-10-16	Park, et al.			
	4	6248637	2001-06-19	Yu			
	5	6432754	2002-08-13	Assaderaghi, et al			

US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
	1	20020142551	2002-10-03	Park, et al.			
	2	20020164841	2002-11-07	Assaderaghi, et al.			
	3	20020115240	2002-08-22	Assaderaghi, et al.			
	4	20020072176	2002-06-13	Park, et al.			

Signature

Examiner Name	Date